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# Timing and Gain Performance of Teledyne e2v's LGADs after Irradiation

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# Teledyne e2v LGAD Project

- University of Birmingham, University of Oxford, RAL and the Open University
- **Teledyne e2v is a foundry based in Chelmsford, UK**
- Established in 1947 (as EEV) to become a major producer of semiconductor imaging sensors (CCDs) and RF solutions for space, astronomy, medical and industrial applications
- **Large production volume capacity** for detectors with fast timing capability would be a big asset to the Particle Physics community



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**TELEDYNE e2v**  
Everywhereyoulook™

Part of the Teledyne Imaging Group



Science and  
Technology  
Facilities Council



The Open  
University



<https://teledyne-e2v.com/en-us>

# Outline



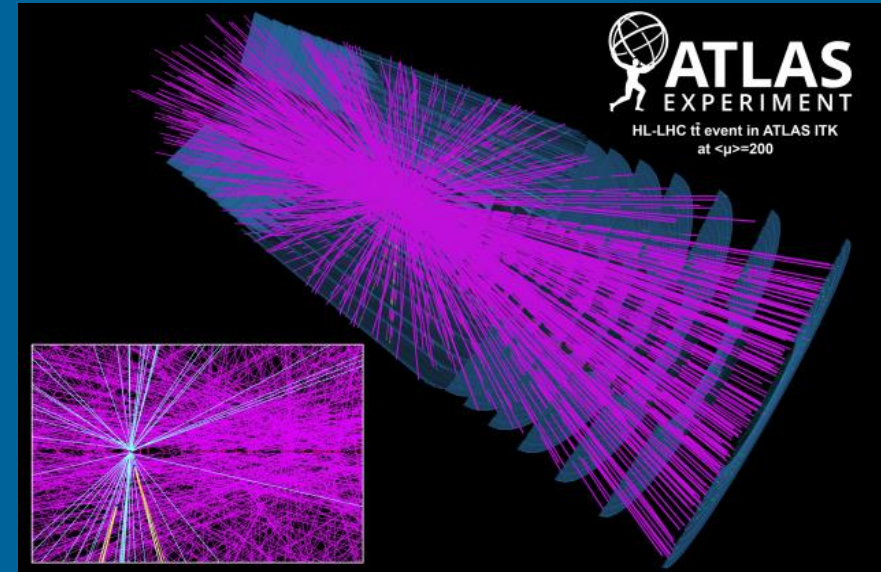
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- Introduction to the project
- Sensor design
- Irradiation campaign
- Characterisation before and after irradiation
  - IVs
  - CVs
  - Gain
  - Timing
- Conclusion

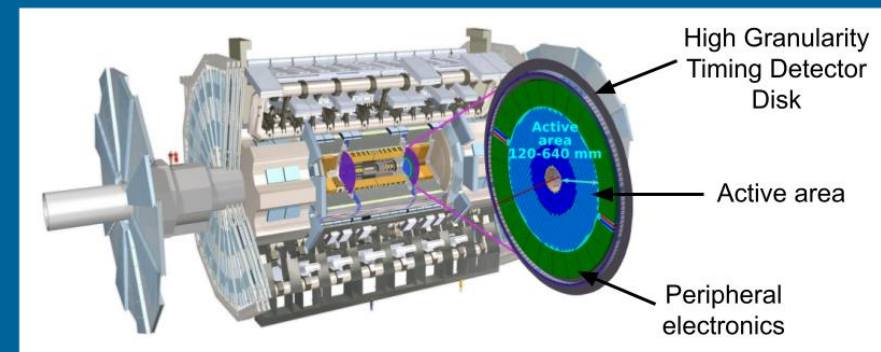
# Why Timing?



- The LHC's High-Luminosity upgrade will see a large **increase in pile-up**, with up to 200 events per 25 ns bunch crossing.
- Overlapping events make track reconstruction challenging and this limits the ability to correctly associate tracks with their primary vertices.
- ATLAS and CMS plan to use a dedicated **rad-hard timing layers equipped with LGADs**. These will be installed outside of the trackers to add fine timing information to each track.
- Later upgrades might look towards LGADs as a replacement for the inner tracking, unlocking true 4D tracking.



<https://cds.cern.ch/record/2674770>

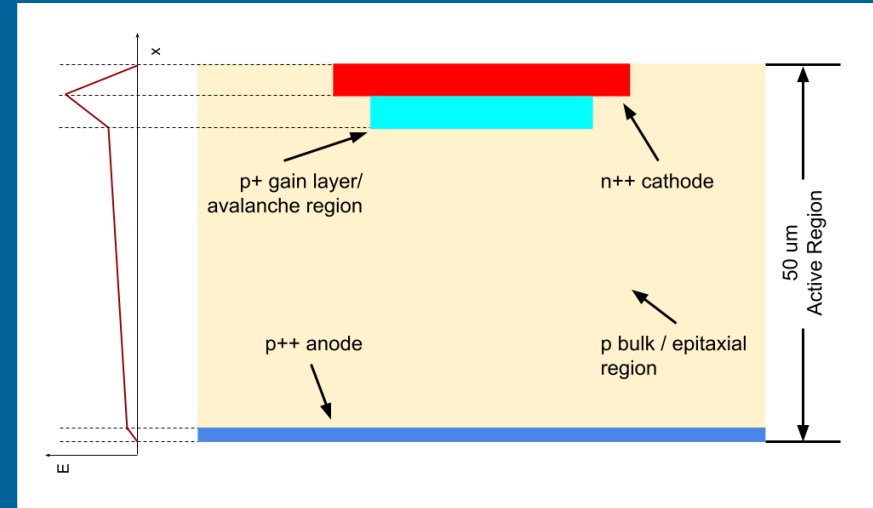


<https://cds.cern.ch/record/2719855?ln=en>

# Low Gain Avalanche Detectors



- LGADs consist of a **thin**, planar n-in-p sensor, with a **multiplication layer** tuned to achieve low/moderate gain
- This design achieves **high S/N**, uniform signal, fast rise time
  - Reduced jitter and distortion terms
  - Reaches physical limit: Landau fluctuations (~20 ps)
  - **Excellent time resolution (~35 ps)**



$$\sigma_t^2 = \sigma_{jitter}^2 + \sigma_{ionization}^2 + \sigma_{distortion}^2 + \sigma_{TDC}^2$$

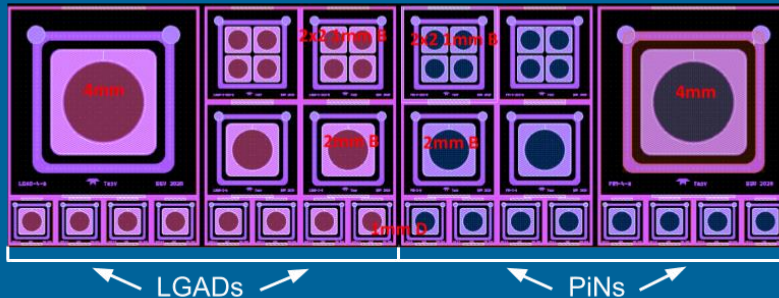
<https://doi.org/10.1016/j.nima.2020.164664>

# TeV 1<sup>st</sup> Batch



- First batch of 22 wafers was fabricated in late 2020 with eight flavours of varying dose and energy of the **Boron implant**
  - 33 test fields per wafer
  - LGAD size varies from 4mm to **1mm**
  - Fields are mirrored with **PiNs** (identical to the LGADs but **without the Boron implant**)
- Initial characterisation presented at the RD50 workshops and various conferences. Today, we'll be focusing on the **1mm** devices from our **most promising wafer (A)** which has the **highest combined implant energy and dose**

Wafer code	Normalised Implant Dose [D]	Normalised Implant Energy [E]
A	1.07	1.11
B	1.07	1.05
C	1.07	1.00
D	0.92	1.05
E	1.15	1.05
F	1.00	1.00
G	1.00	1.05
H	1.00	1.11





# Irradiation Campaign



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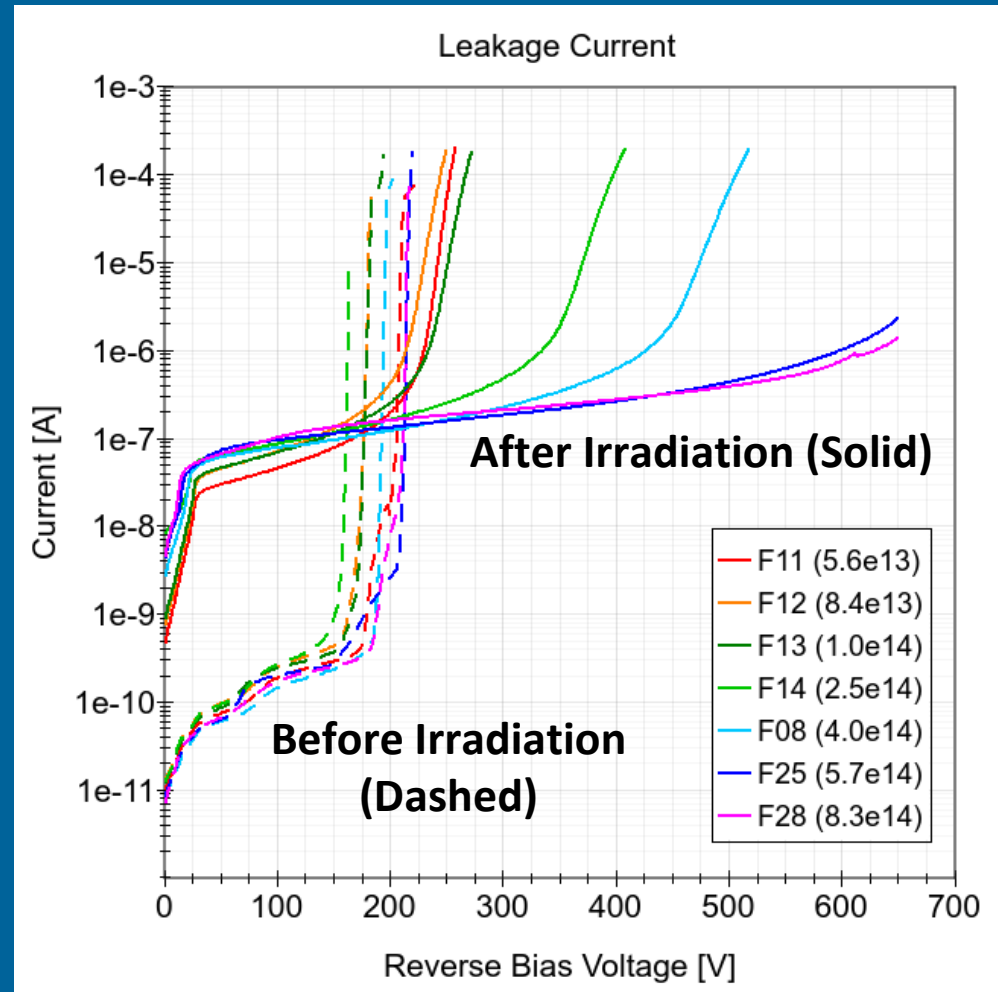
- Seven identical devices have been irradiated with **27 MeV protons** at the **MC40 cyclotron** at **Birmingham**
  - F11-F28 have been irradiated with fluences from **5.6e13 1 MeV neq/cm<sup>2</sup>** up to **8.3e14 1 MeV neq/cm<sup>2</sup>**
- The aim of the study is to investigate how the timing properties of these devices change with fluence due to **acceptor removal** in the gain layer
- The gain layer implant is Boron, **without carbon enrichment**

Device code	Fluence [1 MeV neq/cm <sup>2</sup> ]
F11	5.6e13
F12	8.4e13
F13	1e14
F14	2.5e14
F08	4e14
F25	5.7e14
F28	8.3e14

# IVs



- IV curves are measured to check the highest operating voltage which minimises leakage current
  - Pre-irrad at room temperature
  - Post-irrad at  $-20\text{ }^{\circ}\text{C}$  with low humidity
- **Large variability** ( $\pm 30\text{ V}$ ) in breakdown voltage pre-irradiation
- Change in breakdown voltage increases with fluence as **expected**

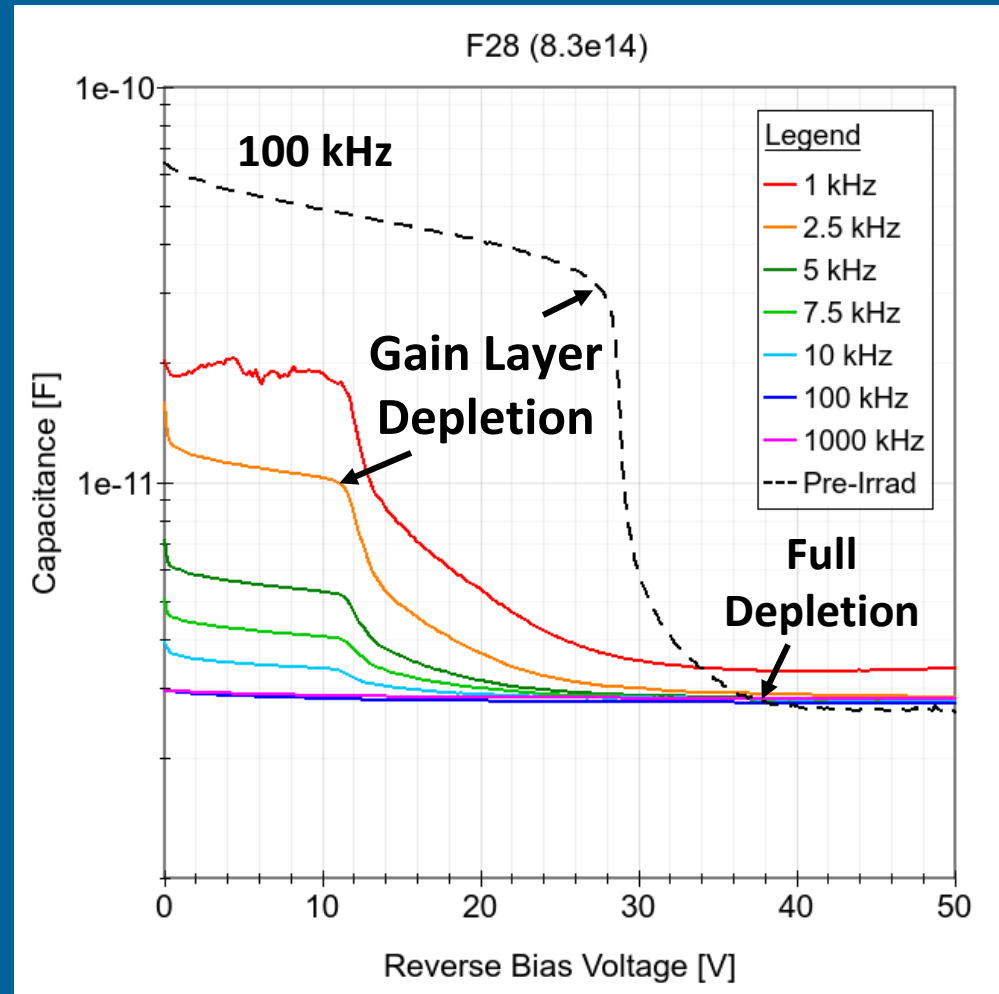




# CVs



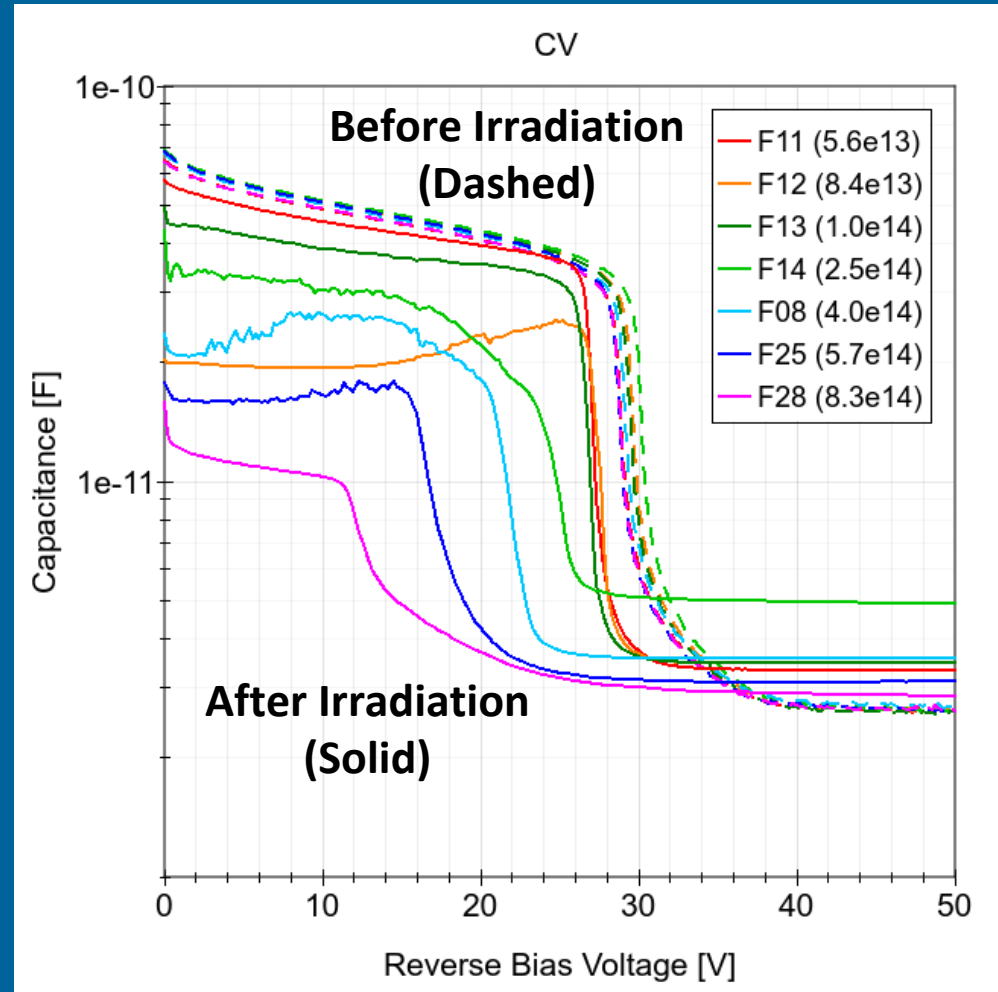
- Determination of gain layer and full **depletion voltage** is done via CV measurements
- For irradiated devices, the **measured capacitance changes** as a function of **frequency**
- At high fluences, full depletion **hard to identify**



# CVs



- Pre-irrad - 100kHz
- Post-irrad - 1kHz
- F28 ( $8.3 \times 10^{14}$ )- 2.5kHz
- Pre-irrad shows very **little variability** in capacitance between devices
- Increasing irradiation fluence results in decreasing depletion voltages



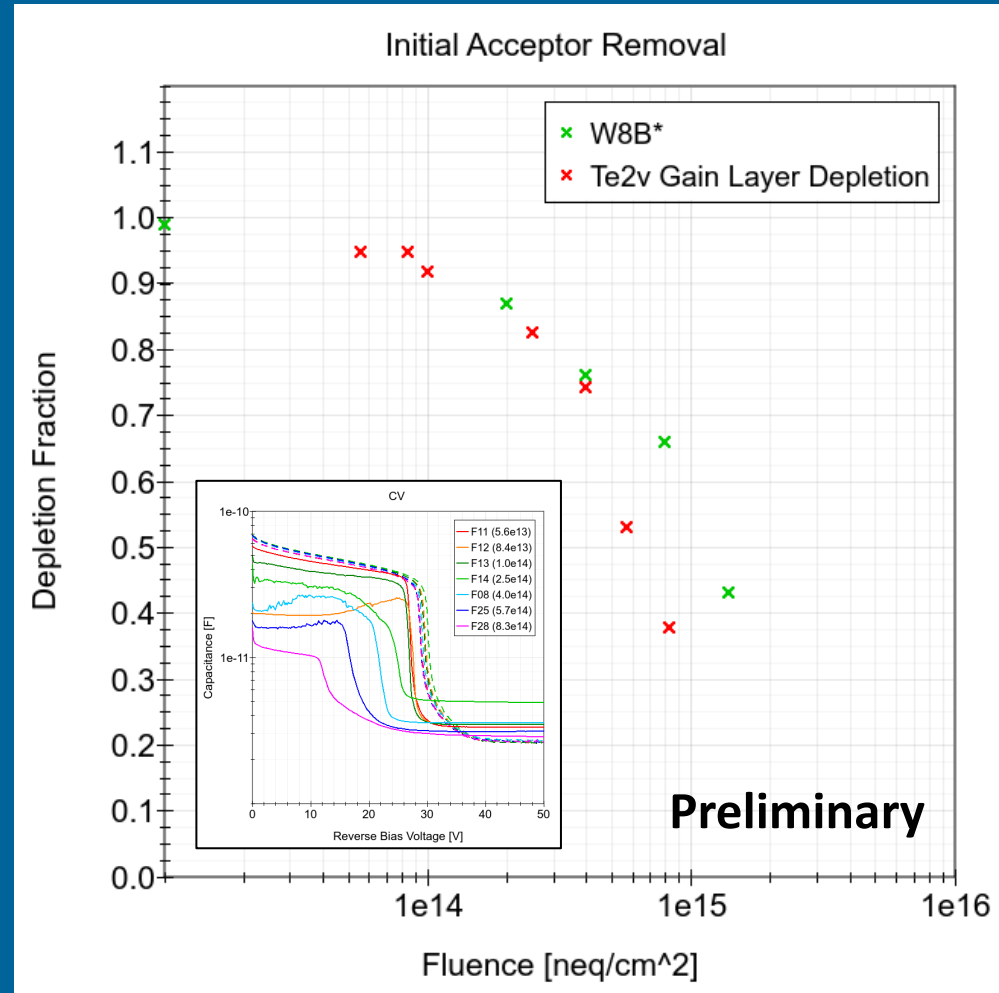
# Parameterising CVs



- The change in gain layer depletion voltage can be characterised by plotting the depletion fraction versus fluence
- For low fluences our results are in agreement. However we demonstrate a **worse radiation hardness** for higher fluences ( $\geq 5.7e14$  1 MeV neq/cm<sup>2</sup>)

\*FBK neutron irradiated Boron-implanted LGADs. Ferreroa, M., 2018

$$\frac{V_{GL}(\phi)}{V_{GL}(0)} = \frac{\rho_A(\phi)}{\rho_A(0)} = e^{-c(\rho_A(0))\phi}$$

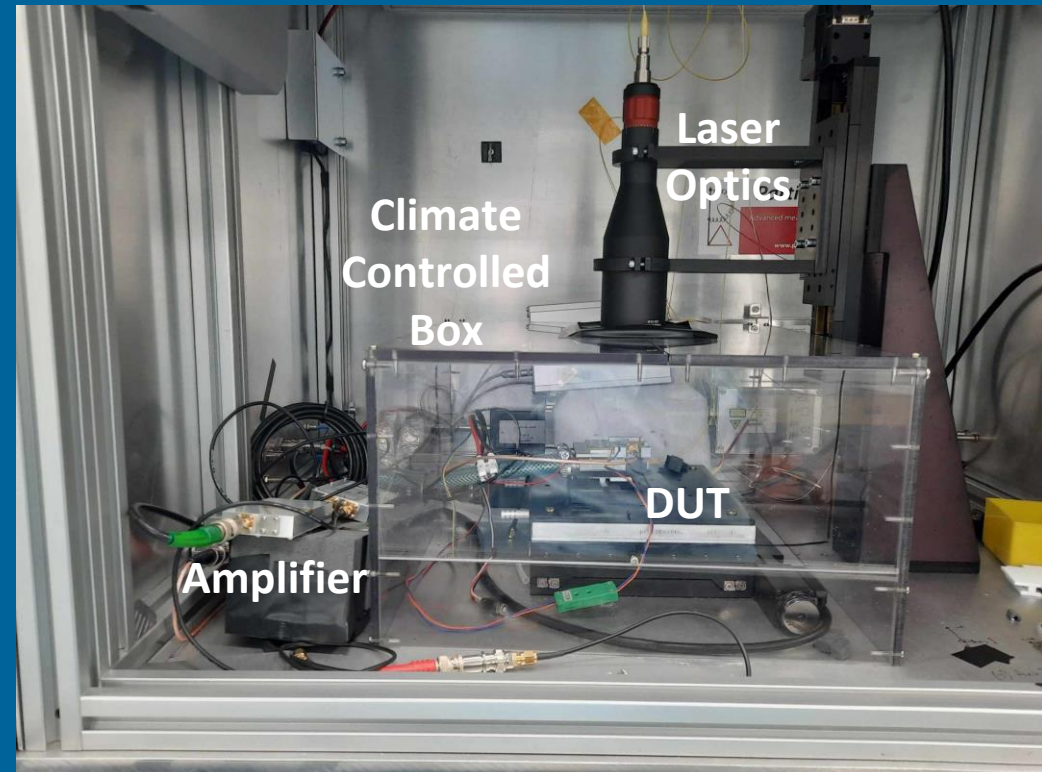


<https://arxiv.org/pdf/1802.01745.pdf>

# Laser Charge Injection



- **1064 nm** laser injects charge into an LGAD and a PiN (LGAD without gain layer)
  - Pulse is integrated and amplified by a Particulars AM-02A
  - Resulting signal is integrated (offline) and the **ratio between the LGAD and the PiN is the gain**
- Laser is convenient but, unlike with charged particles, there is no gain suppression

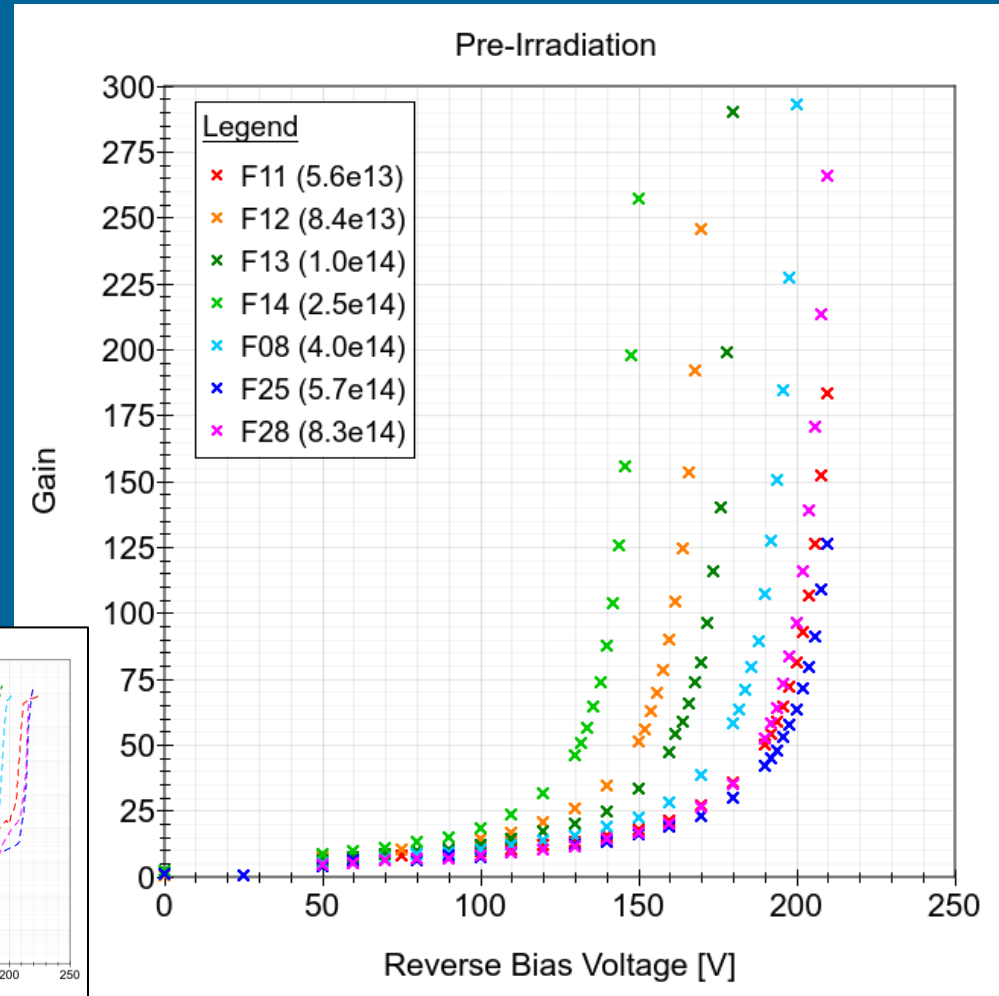
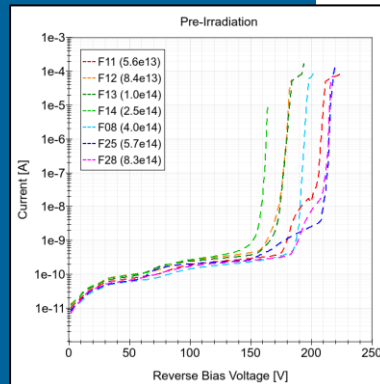


<https://www.particulars.si/downloads/ParticularsAmps-Manuals.pdf>

# Pre-Irrad Gain



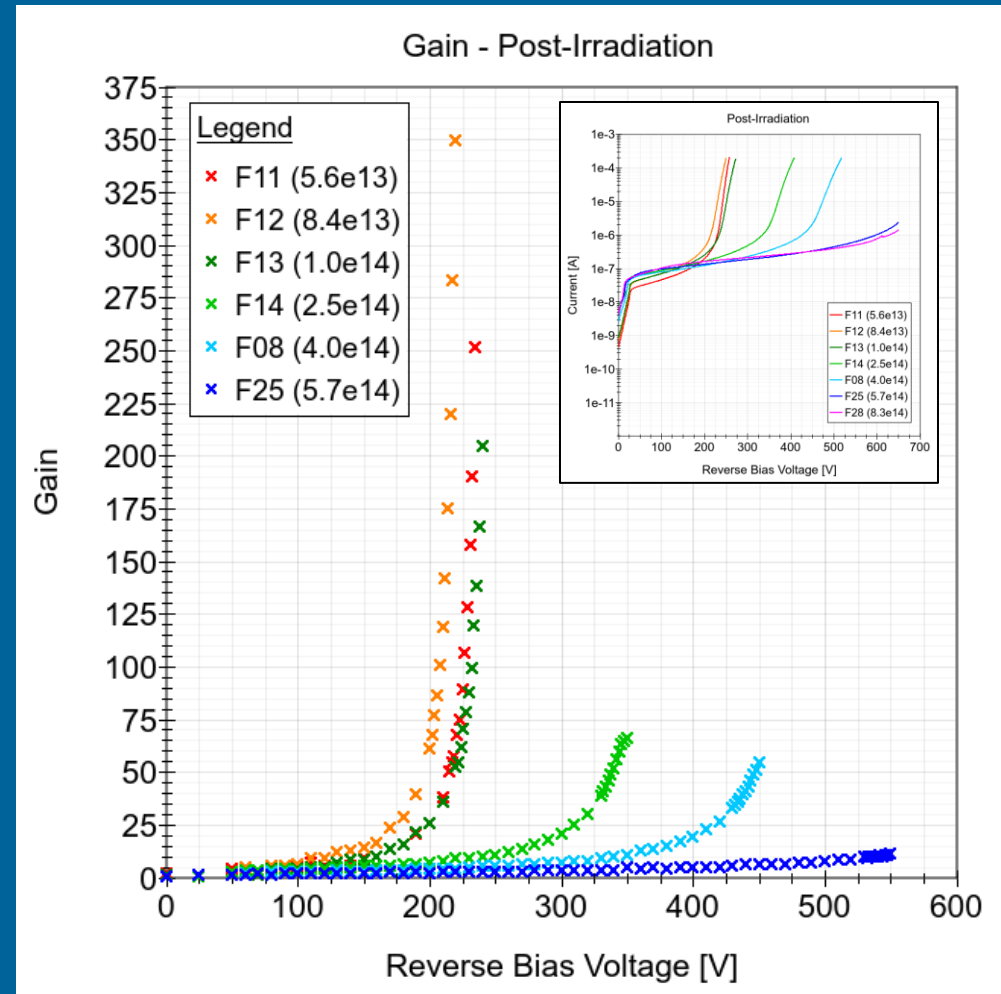
- All devices achieve a similar value of gain, but the bias voltage required varies significantly
- This is mirrored in the IV curves which also have a similar variance in breakdown voltage



# Post-Irrad Gain



- **Low fluence** devices see **minimal change** aside from a slight change in bias voltage dependence
- With **higher fluences** one is **unable to achieve as high a value of gain**. A higher bias voltage is also needed to see moderate gain

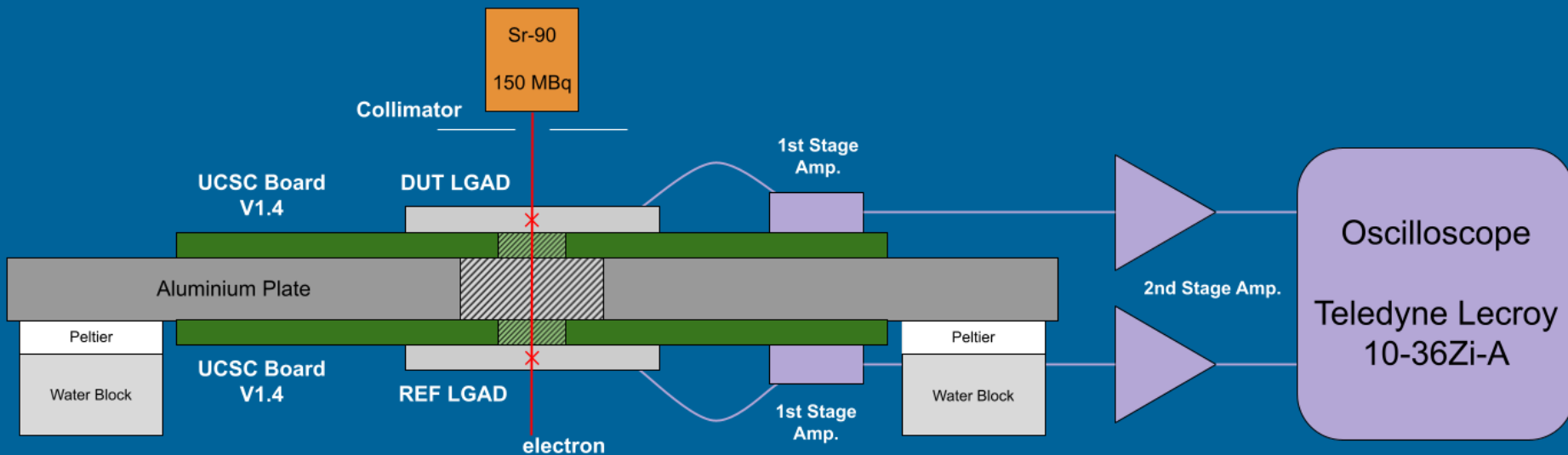


# Coincidence Timing Technique



- Strontium-90 beta source injects **charged particles** towards two **coincidently placed LGADs** (DUT and a reference of known time resolution). Oscilloscope triggers on the two LGAD pulses provided they are within 5 ns of each other

- Santa Cruz timing boards initially amplify the signal, followed Particulars AM-01B for 2nd stage amplification. The resulting signal is recorded for offline analysis



<https://arxiv.org/pdf/1707.04961.pdf>

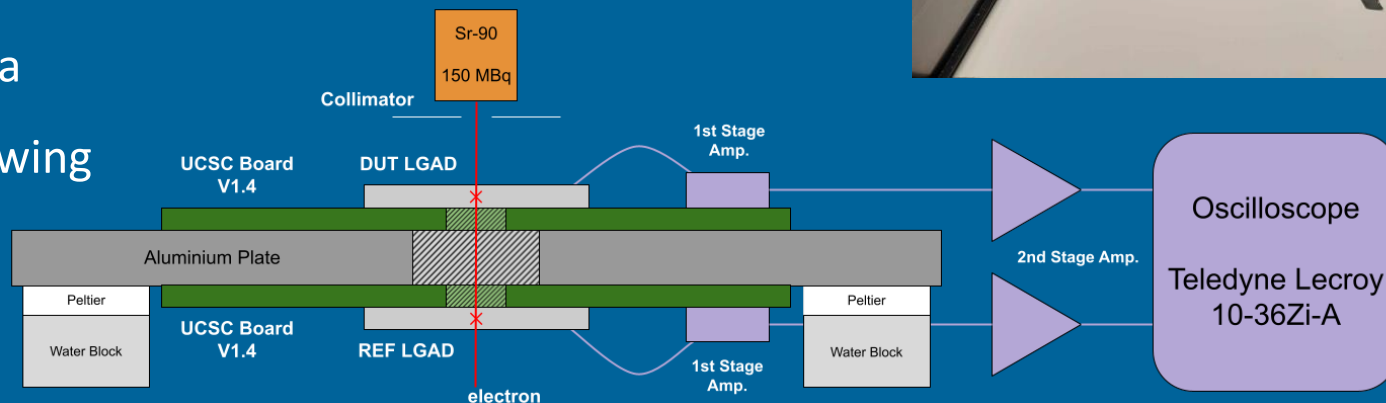
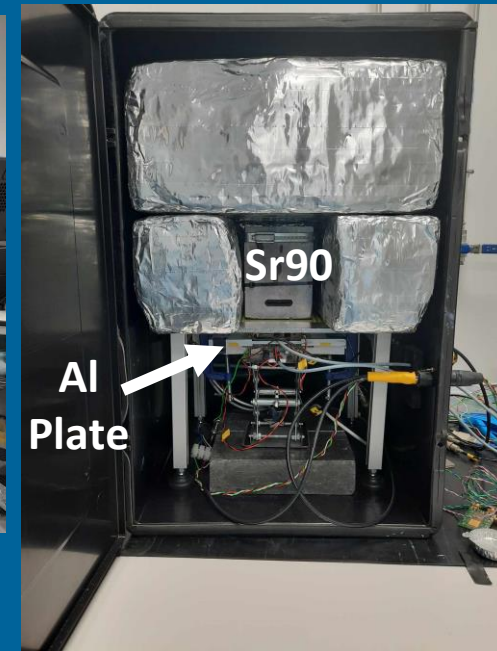
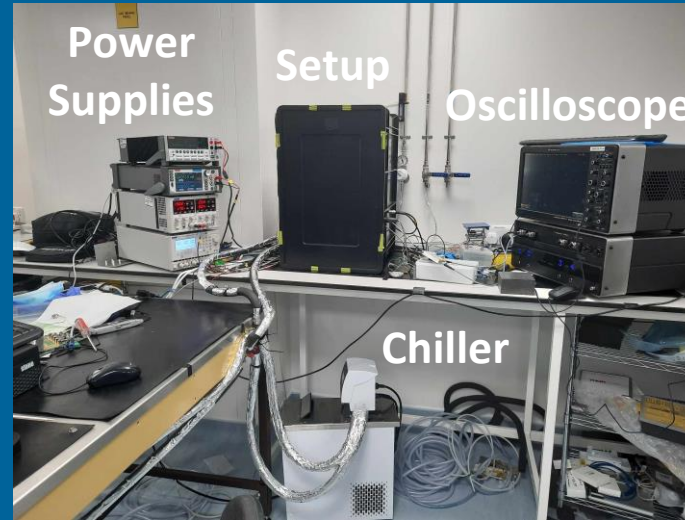
<https://www.particulars.si/downloads/ParticularsAmps-Manuals.pdf>



# Cold Timing



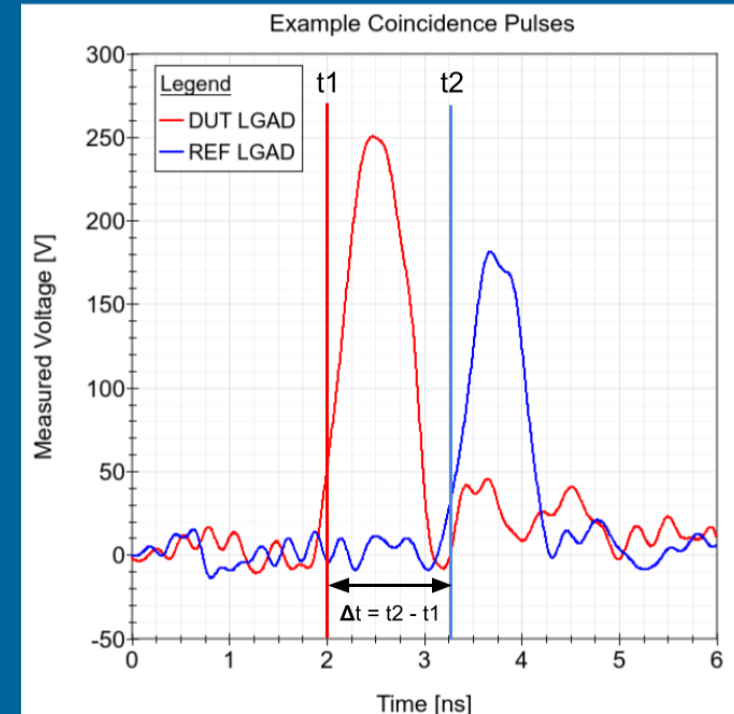
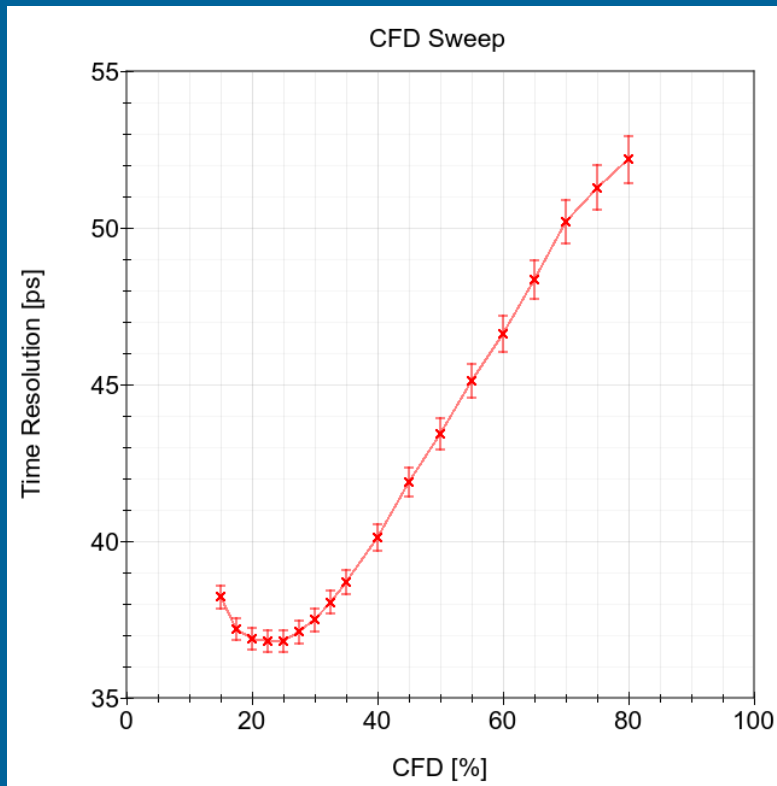
- A pair of peltiers (assisted by a chiller) keep the LGADs at  $-20\text{ }^{\circ}\text{C}$  for post-irradiation tests
- Aluminium plate is sandwiched between the LGADs to provide a thermal mass allowing **uniform cooling**



# Time of Arrival



- A single electron triggers both LGADs with an **arbitrary constant time** difference the error of which is dominated by the time resolution of the two LGADs



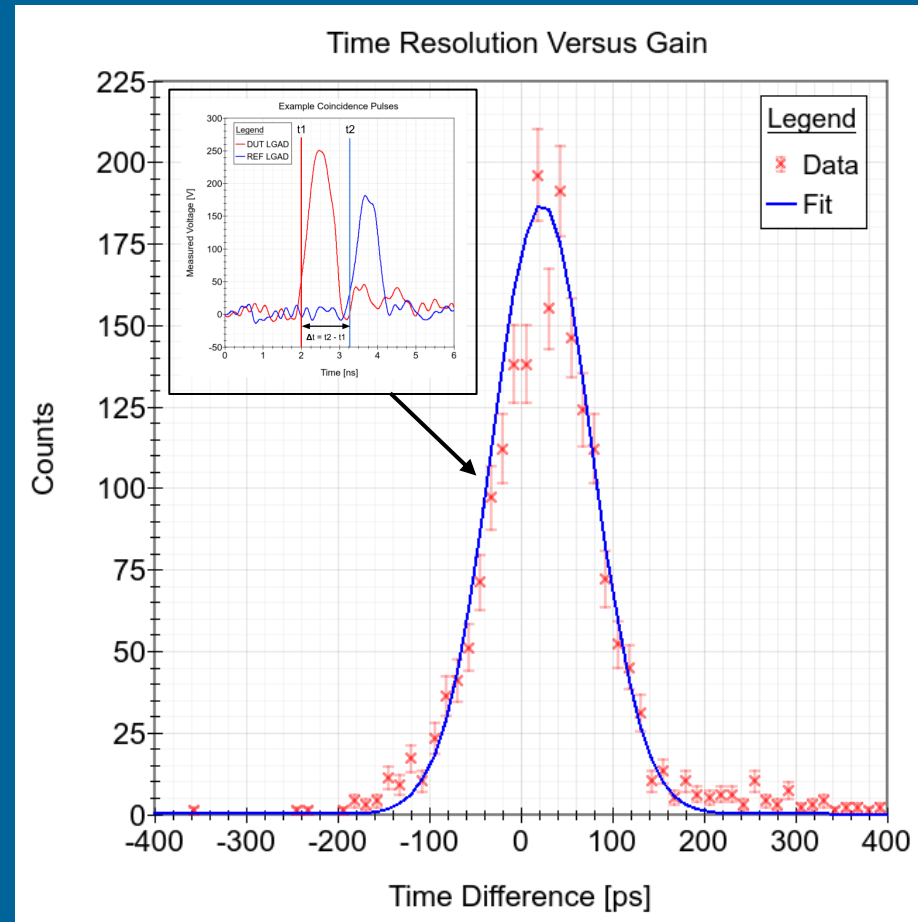
- Time of arrival is determined with a **20% constant fraction discriminator (CFD)** applied offline to the collected data. This was determined by performing a **CFD sweep** to identify the optimal value

# Time Resolution



- After ~2000 coincidence events have been collected one can fit a Gaussian distribution (represented visually with a histogram)
- This Gaussian is a product of the two LGAD time resolutions
- Thus the resolution of the reference needs to be subtracted in quadrature from the measured Gaussian's standard deviation

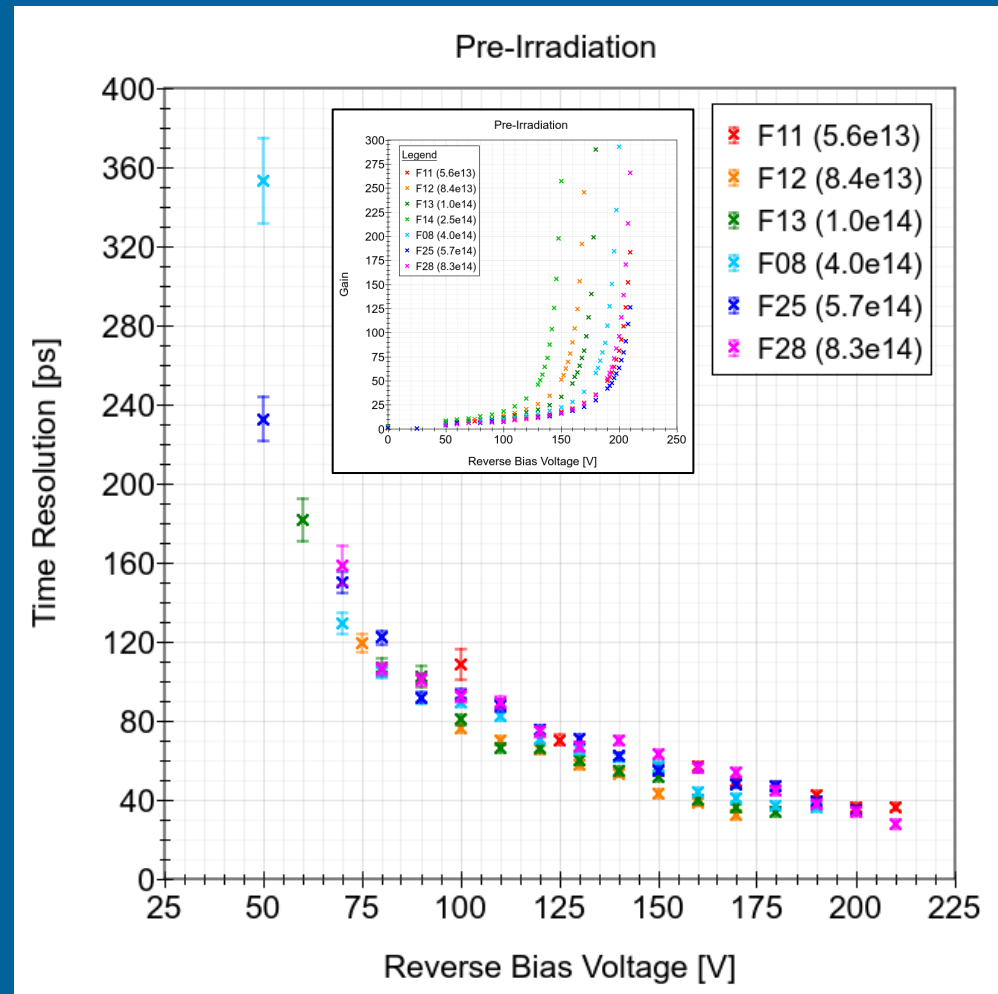
$$\sigma_{MEAS}^2 = \sigma_{DUT}^2 + \sigma_{REF}^2$$



# Pre-Irrad Timing



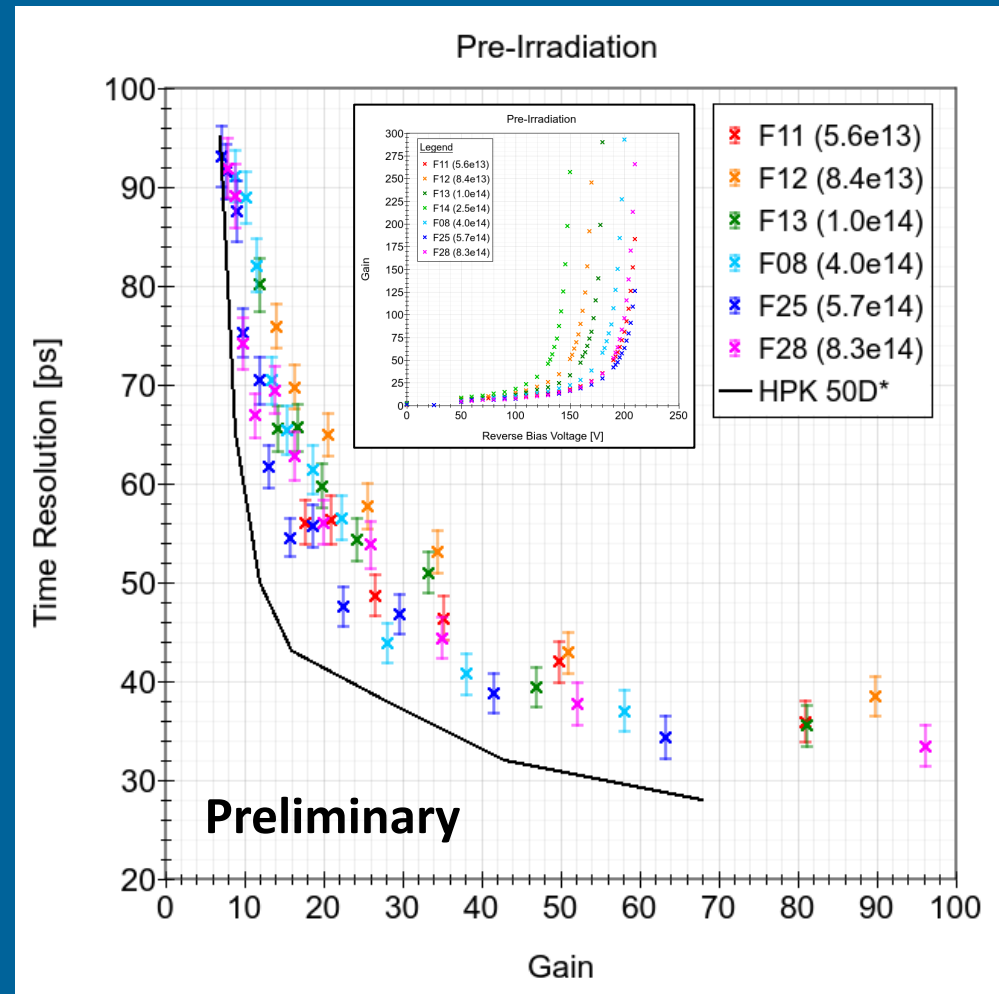
- All 7 devices show a **similar timing performance versus bias voltage**
- Minimal variability corresponds to the **variation in gain as a function of voltage**



# Pre-Irrad Timing



- Time resolution as a function of gain shows a **similar trend** to what we see from other vendors
- While comparable, our **time resolution is slightly worse** than those from HPK (\*)
- However, values of gain may be overestimated using laser injection (no gain suppression)

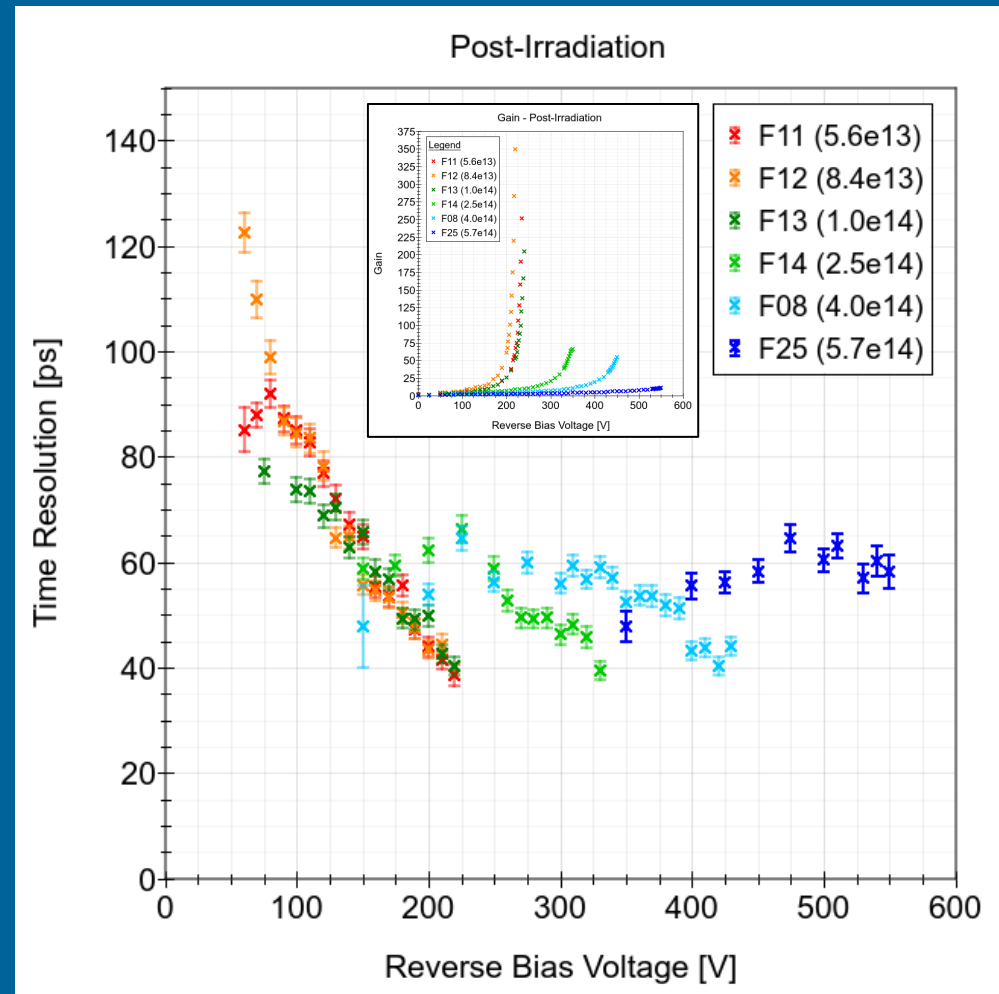


<https://indico.cern.ch/event/587631/contributions/2471694>

# Post-Irrad Timing



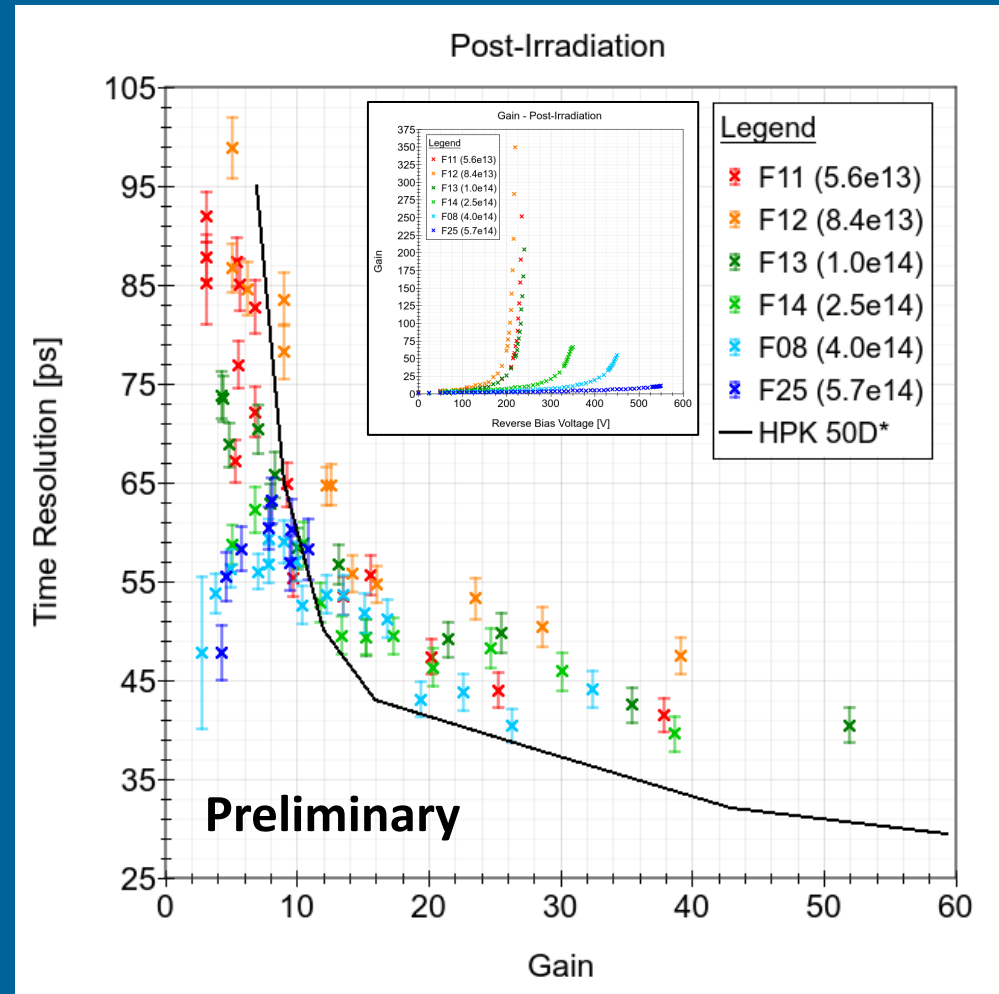
- As seen with gain, a **higher bias is required** to achieve a good time resolution as fluence increases
- **Time resolution is generally worse compared to pre-irrad** (sub 40ps)
- We were unable to test F28 due to unstable current at high bias voltages



# Post-Irrad Timing



- Time resolution as a function of gain maintains the **same relationship** after irradiation
- At low values of gain, the time resolution begins to improve. This is due to some signals falling below the oscilloscope's trigger threshold, **biasing the data towards only including the largest signals**. This has been confirmed by lowering the trigger threshold



<https://indico.cern.ch/event/587631/contributions/2471694>



# Conclusions



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- Teledyne e2v is a **new player** for Particle Physics applications, demonstrated with their **first batch** of LGADs
  - **Slightly worse but comparable timing performance**
  - **Radiation hardness needs further investigation and improvement at higher fluences ( $\geq 5.7 \times 10^{14} \text{ 1 MeV neq/cm}^2$ )**
- Promising results from their first batch establishes them as a potential future vendor for the Particle Physics community
- In addition to the 7 devices shown today, we plan to characterise up to 4 additional wafers to investigate the effect of implant energy and dose



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# Thank you for your time

Any questions?



# Previous Talks



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- 37th RD50 workshop, Nov 2020
  - <https://indico.cern.ch/event/896954/contributions/4106308/>
- 38th RD50 workshop, June 2021
  - <https://indico.cern.ch/event/1029124/contributions/4411263/>
  - <https://indico.cern.ch/event/1029124/contributions/4411247/>
- PSD12, Sept 2021 (+ proceedings)
  - <https://indico.cern.ch/event/797047/contributions/4455947/>
- Vertex, Sept 2021 (+ proceedings)
  - <https://indico.cern.ch/event/1047531/contributions/4520803/>
- 39th RD50 workshop, Nov 2021
  - <https://indico.cern.ch/event/1074989/contributions/4601996/>
  - <https://indico.cern.ch/event/1074989/contributions/4602008/>
- 17th Trento Workshop, March 2022
  - <https://indico.cern.ch/event/1096847/contributions/4743794/>

# Backup Slides

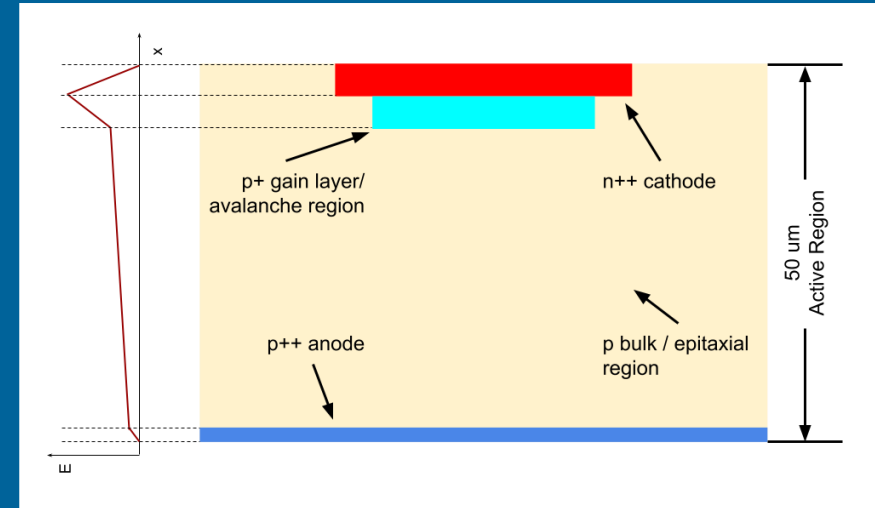


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# Low Gain Avalanche Detectors



- We study LGADs for their excellent time resolution ( $\sim 35$  ps). This time resolution has a few contributions
- **Distortion** is due non-uniformity in the drift velocity and weighting field. High bias voltage ensures a saturated and uniform drift velocity. Ensuring the gain layer is as large as the pitch of the sensor keeps the weighting field uniform
- **TDC** is due to the readout electronics and is usually small enough to be ignored

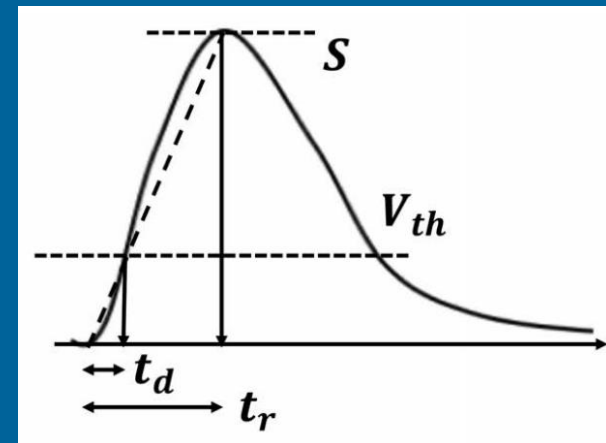
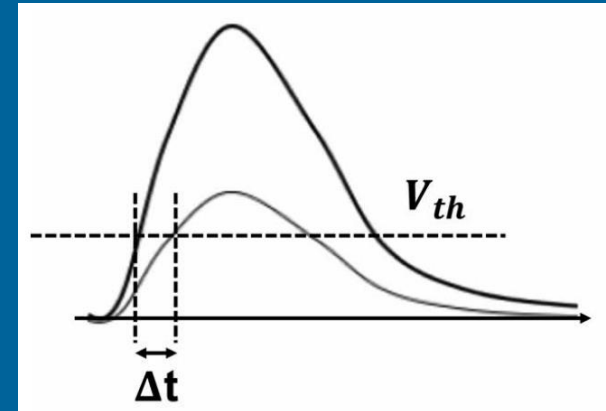


$$\sigma_t^2 = \sigma_{jitter}^2 + \sigma_{ionization}^2 + \sigma_{distortion}^2 + \sigma_{TDC}^2$$

# Low Gain Avalanche Detectors



- **Ionisation** is due to the irregularity in the signal shape caused by the discrete nature of e-h pair generation
- The first effect is a change in amplitude which causes timewalk (a larger signal arrives earlier). This can be corrected for using a Constant Fraction Discriminator (CFD)
- The second effect is called Landau Fluctuations and is due to irregularities and noise in the signal shape itself. These fluctuations are unavoidable but can be minimised with thin sensors ( $\sim 50 \mu\text{m}$ ) which bring this intrinsic limit down to  $\sim 25 \text{ ps}$

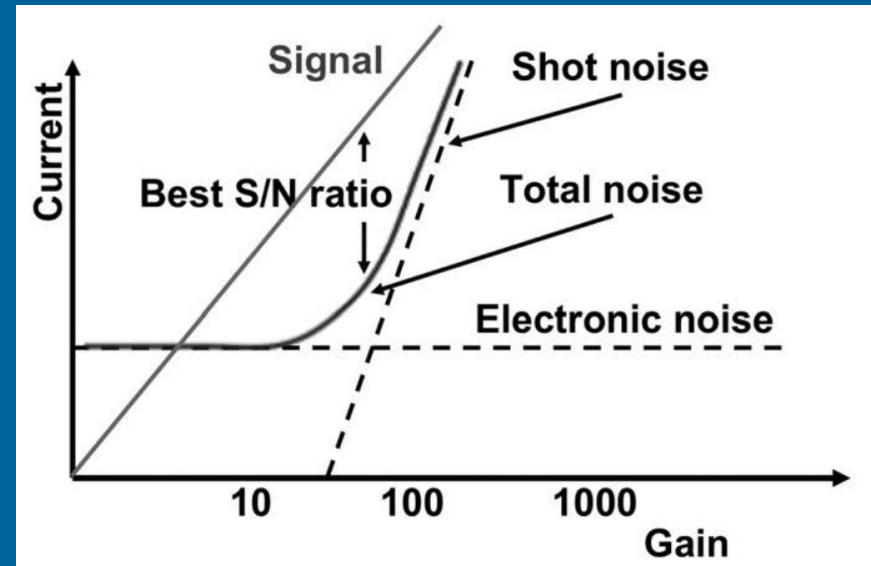


$$\sigma_t^2 = \sigma_{jitter}^2 + \sigma_{ionization}^2 + \sigma_{distortion}^2 + \sigma_{TDC}^2$$

# Low Gain Avalanche Detectors



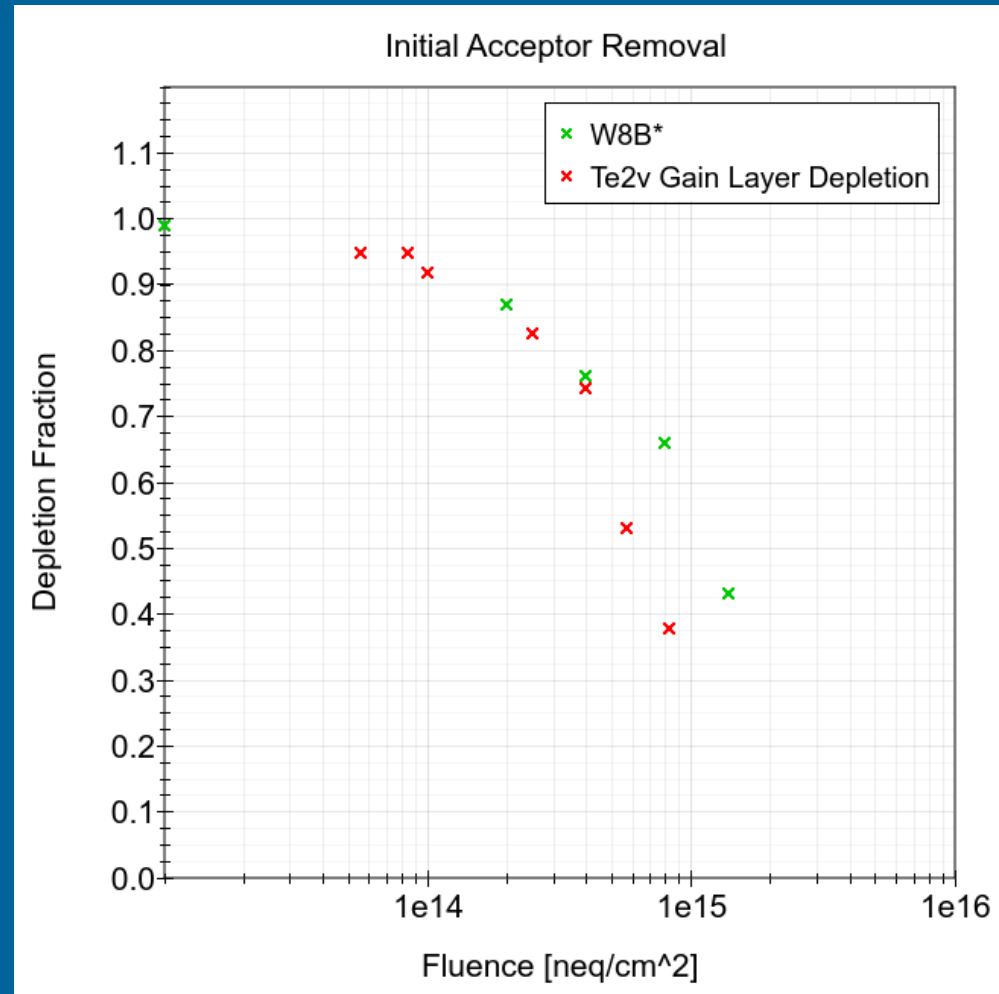
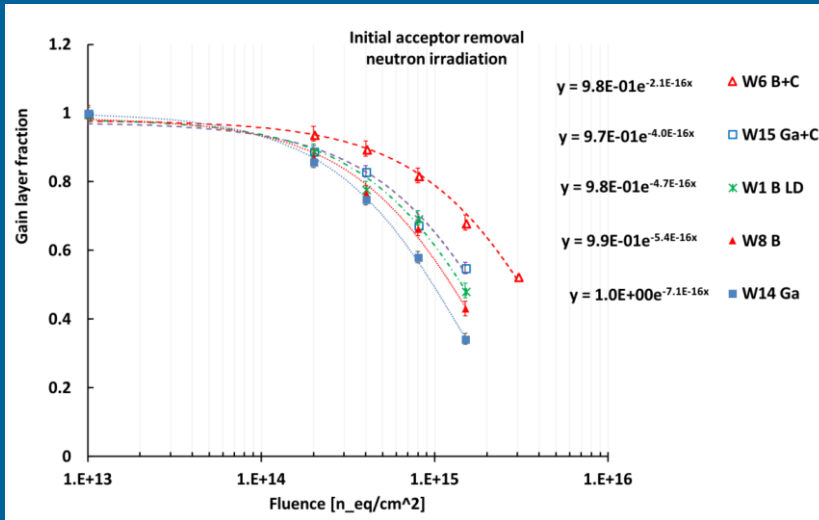
- **Jitter** is any additional noise on top of the signal which can cause the signal to appear to arrive earlier or later than it actually does.
- For a constant slope in the rise of the signal, the jitter is approximately proportional to the rise time divided by the SNR.
- A low gain maximises the SNR which therefore minimises the jitter. Hence low gain gives good time resolution.



$$\sigma_t^2 = \sigma_{jitter}^2 + \sigma_{ionization}^2 + \sigma_{distortion}^2 + \sigma_{TDC}^2$$



# Parameterising CVs



\*FBK neutron irradiated Boron-implanted LGADs. Ferreroa, M., 2018

$$\frac{V_{GL}(\phi)}{V_{GL}(0)} = \frac{\rho_A(\phi)}{\rho_A(0)} = e^{-c(\rho_A(0))\phi}$$

<https://arxiv.org/pdf/1802.01745.pdf>

# Reference Time Resolution



- If we don't have a device of known time resolution, we have two options:
- The first is to use two identical LGADs and assume their time resolutions are the same. This results in the second equation. This is most likely a reasonable estimate and then gives us a reference device, however we can improve on this method to remove the assumption.
- The second option is to measure 3 LGADs (identical or not) in 3 sets of pairs (third set of equations). Then by combining these in a particular order, we can extract the time resolution of each device.
- Whilst this provides us with a reference device, it currently yields a rather high error which has a knock-on effect with future measurements.

$$\sigma_{MEAS}^2 = \sigma_{DUT}^2 + \sigma_{REF}^2$$

$$\sigma_{DUT} = \frac{\sigma_{MEAS}}{\sqrt{2}}$$

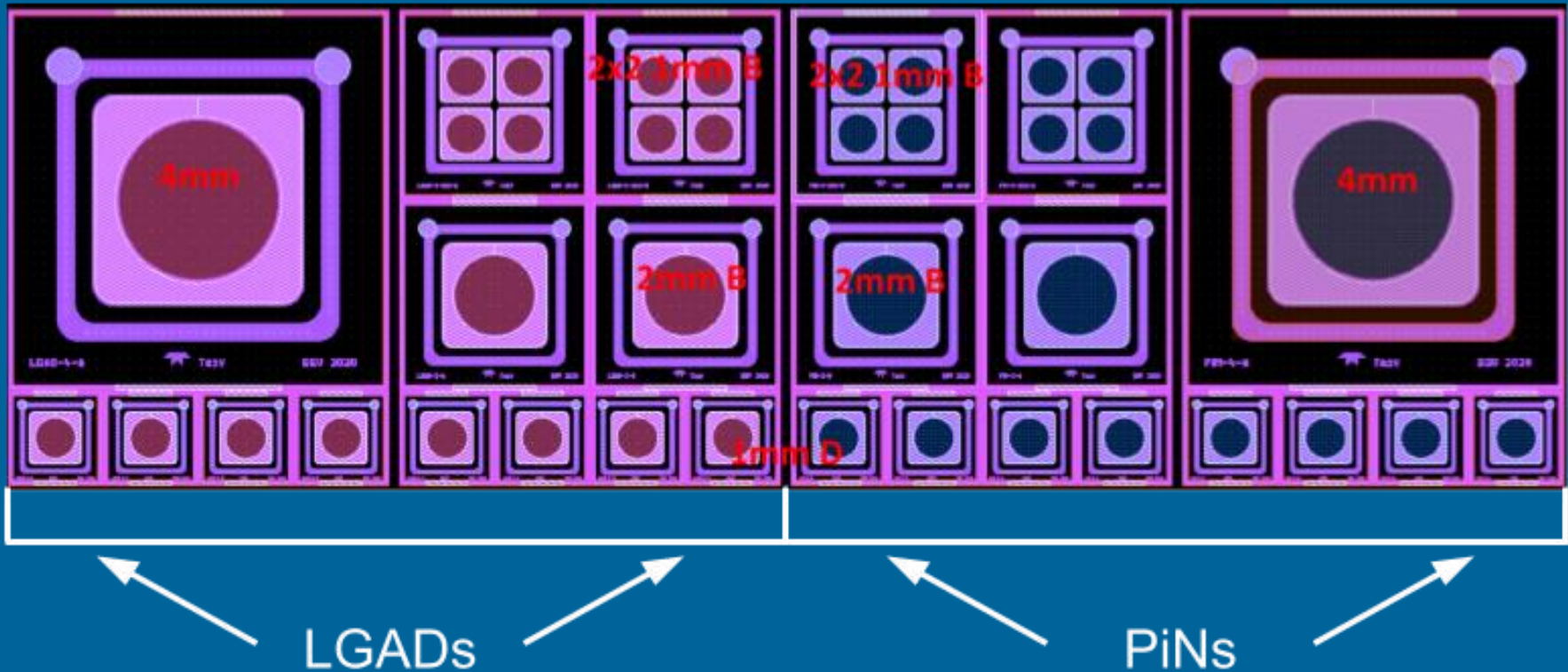
$$\sigma_1^2 = \sigma_A^2 + \sigma_B^2,$$

$$\sigma_2^2 = \sigma_C^2 + \sigma_B^2,$$

$$\sigma_3^2 = \sigma_A^2 + \sigma_C^2,$$

$$\sigma_1^2 + \sigma_2^2 - \sigma_3^2 = 2\sigma_B^2$$

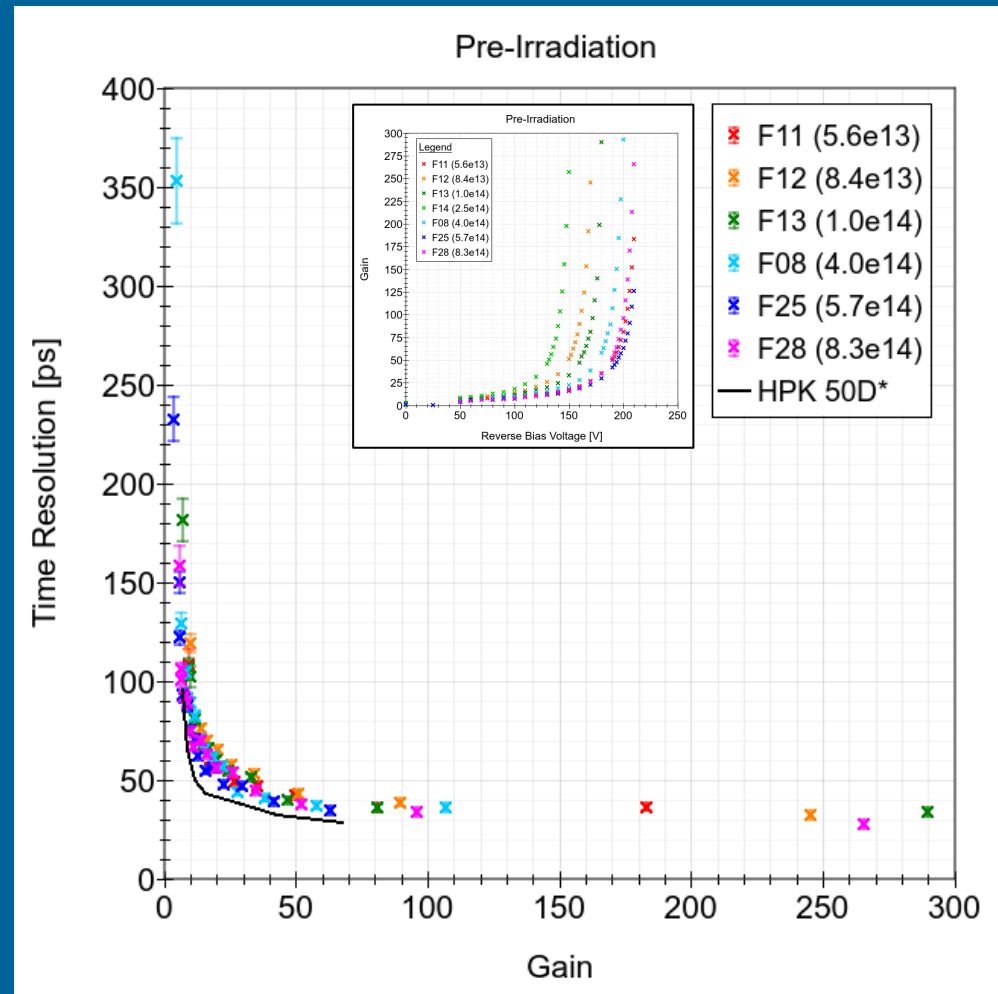
# 1<sup>st</sup> Batch



# Pre-Irrad Timing



- Time resolution as a function of gain shows a similar trend to what we see from other vendors
- While comparable, our time resolution is slightly worse than the literature
- However, values of gain may be overestimated using laser injection (no gain suppression)

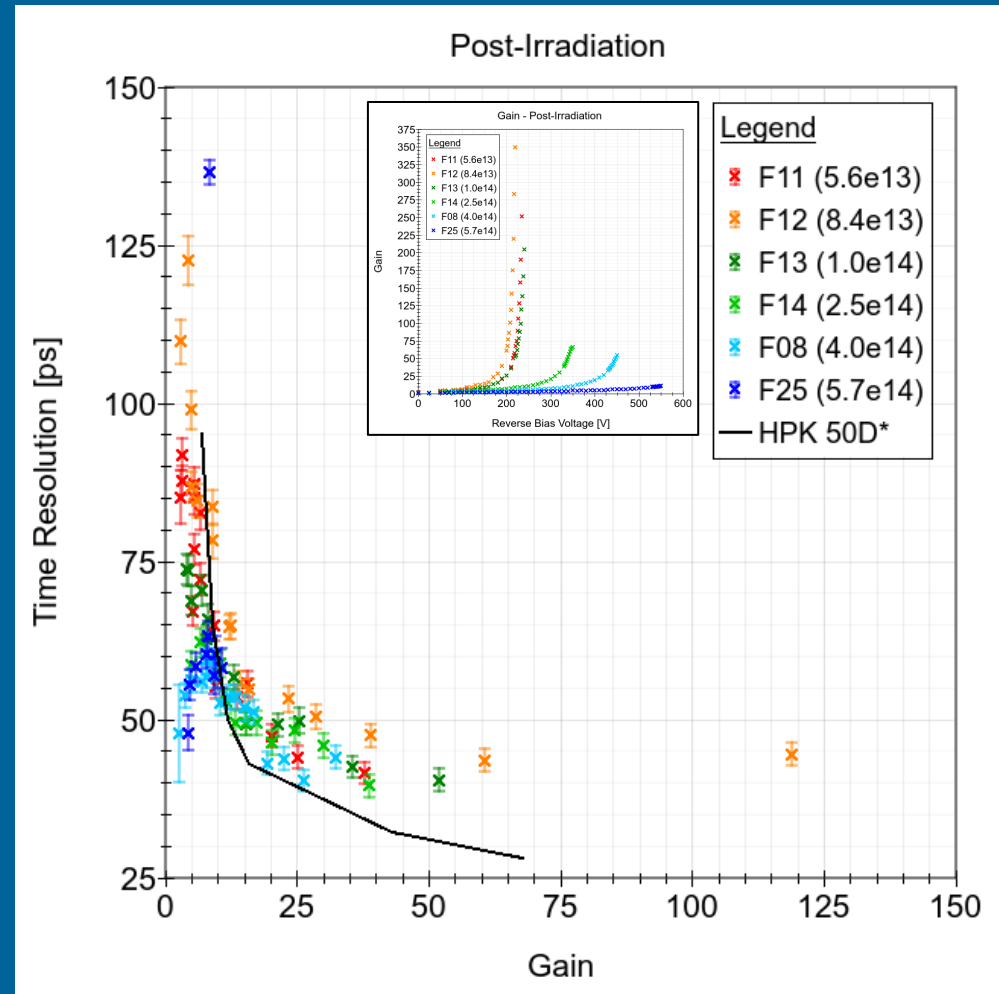


\*Sadrozinski, H., Ultra-fast Silicon Detectors, 2017 <https://arxiv.org/abs/1704.08666>

# Post-Irrad Timing



- Time resolution as a function of gain maintains the same relationship after irradiation
- At low values of gain, the time resolution begins to improve. This is due to some signals falling below the oscilloscope's trigger threshold, biasing the data towards only including the largest signals. This has been confirmed by lowering the trigger threshold

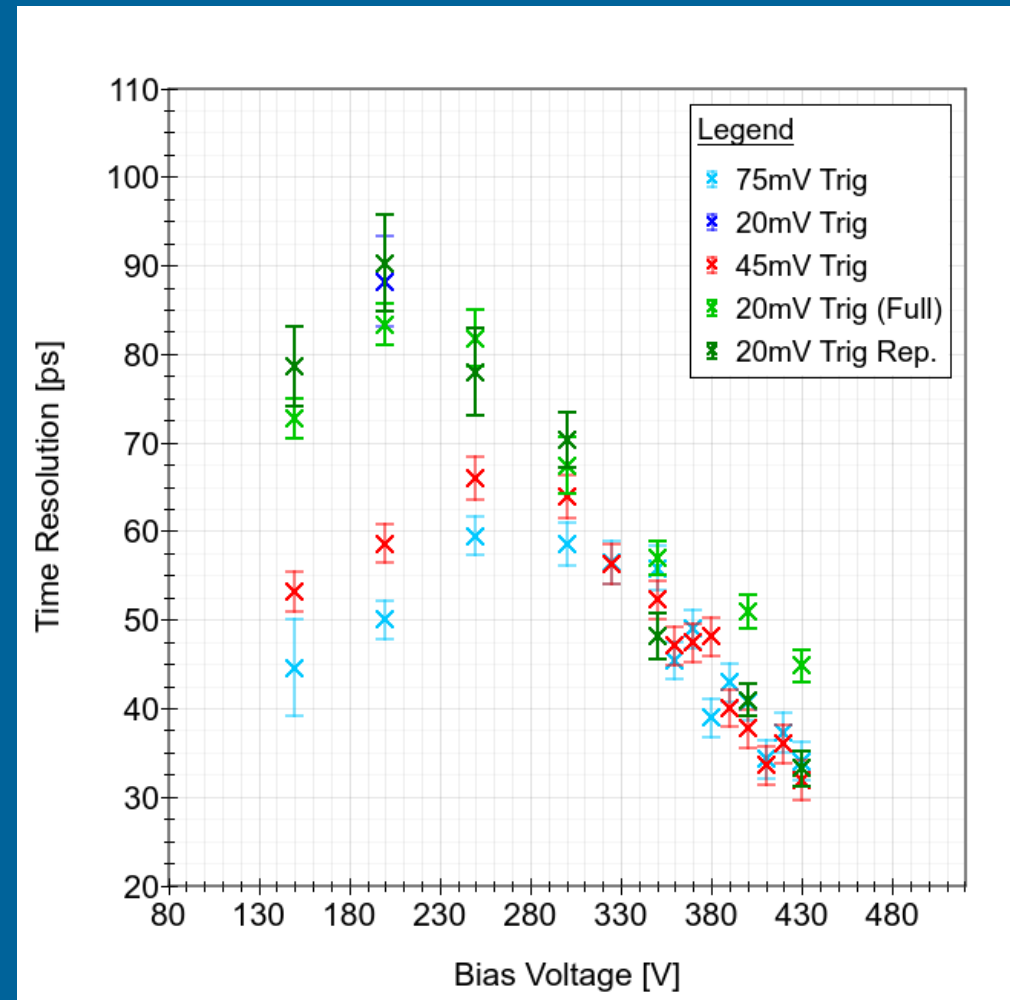


\*Sadrozinski, H., Ultra-fast Silicon Detectors, 2017 <https://arxiv.org/abs/1704.08666>

# Landau Cutting



- Bias sweep performed at different trigger thresholds
- Higher thresholds give a better time resolution since only large signals are accepted
- Higher thresholds are sometimes still used to make the measurement speed practical



# Landau Cutting



- Signal height for 2000 events are plotted as a histogram. Each curve shows a different trigger threshold. Plot on the left shows high bias and trigger threshold has no effect. Right plot shows low bias and the trigger significantly changes the distribution

